L Number	Hits	Search Text	DB	Time stamp
1	693	electroluminesce$2 and implant$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/29 11:40
2	193681	light near emit$4 near (diode or device or element)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/29 11:42
3	51	(electroluminesce$2 and implant$3) and anodiz$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/29 11:43
4	842	(light near emit$4 near (diode or device or element)) and anodiz$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/29 11:43
5	22	((electroluminesce$2 and implant$3) and anodiz$3) and (porous near silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/29 11:44
6	99	((light near emit$4 near (diode or device or element)) and anodiz$3) and (porous near silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/29 11:44